# **SPECIFICATION** K-no.: 26020 (electronic circuit) Customer: Standard type

Item no.: T60404-N4646-X762

Date:

15 A Current Sensor for 5V- Supply Voltage

For electronic current measurement: DC, AC, pulsed, mixed ..., with a galvanic isolation between primary circuit (high power) and secondary circuit

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Customers Part no .:

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# Description

- Closed loop (compensation) Current Sensor with magnetic field probe
- Printed circuit board mounting
- Casing and materials UL-listed

# Characteristics

- Excellent accuracy
- Very low offset current
- Very low temperature dependency and offset current drift
- Very low hysteresis of offset current
- Short response time
- Wide frequency bandwidth
- Compact design
- Reduced offset ripple

#### **Applications**

Mainly used for stationary operation in industrial applications:

- AC variable speed drives and servo motor drives
- Static converters for DC motor drives
- Battery supplied applications
- Switched Mode Power Supplies (SMPS)
- Power Supplies for welding applications
- Uninterruptible Power Supplies (UPS)

#### **Electrical data - Ratings**

I <sub>PN</sub>	Primary nominal r.m.s. current	15	А
$V_{out}$	Output voltage @ IP	$V_{Ref} \pm (0.625*I_P/I_{PN})$	V
Vout	Output voltage @ I <sub>P</sub> =0, T <sub>A</sub> =25°C	$V_{Ref} \pm 0.00225$	V
$V_{Ref}$	External Reference voltage range	04	V
	Internal Reference voltage	2.5 ±0.005	V
K <sub>N</sub>	Turns ratio	14 : 2000	

### Accuracy - Dynamic performance data

		min.	typ.	max.	Unit
I <sub>P,max</sub>	Max. measuring range	±51			
Χ	Accuracy @ I <sub>PN</sub> , T <sub>A</sub> = 25°C			0.7	%
$\epsilon_{L}$	Linearity			0.1	%
$V_{out}$ - $V_{Ref}$	Offset voltage @ I <sub>P</sub> =0, T <sub>A</sub> = 25°C			±2.21	mV
$\Delta V_o / V_{Ref} / \Delta T$	Temperature drift of $V_{out}$ @ $I_P=0$ , $V_{Ref}=2.5V$ , $T_A=-40$	085°C	2.3	20	ppm/°C
$t_{r}$	Response time @ 90% von I <sub>PN</sub>		300		ns
Δt (I <sub>P,max</sub> )	Delay time at di/dt = 100 A/μs		200		ns
f	Frequency bandwidth	DC200			kHz

#### General data

		min.	typ.	max.	Unit
T <sub>A</sub>	Ambient operating temperature	-40		+85	°C
Ts	Ambient storage temperature	-40		+105	°C
m	Mass		12		g
Vc	Supply voltage	4.75	5	5.25	V
Ic	Current consumption		15		mA

Constructed and manufactored and tested in accordance with EN 61800-5-1 (Pin 1 - 4 to Pin 5 - 12) Reinforced insulation. Insulation material group 1. Pollution degree 2

	3 · · ·			
Sclear	Clearance (component without solder pad)	9.6		mm
Screep	Creepage (component without solder pad)	10.6		mm
$V_{sys}$	System voltage overvoltage category 3	RMS	600	V
Vwork	Working voltage	RMS	1060	V
UPD	Rated discharge voltage	peak value	1320	V

Note: "According UL 508: Max. potential difference = 600 VA

Date	Name	Issue	Amendment						
31.01.2022	NSch.	83	Applicable do	oplicable documents changed on sheet 3. "The color of the plastic material added. Minor change					
05.02.14	Ga.	83	Marking chan	larking changed acc to UL-specification. 4646X762-82 → 4646-X762-83. CN-923					
Hrsg.: KB	S-E		arb: Le		KB-PM: Ga.			freig.:SB released	



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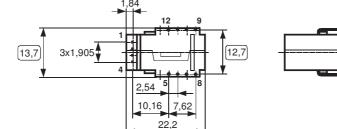
Customer: Standard type Mechanical outline (mm):

General tolerances DIN ISO 2768-c

Customers Part no.:

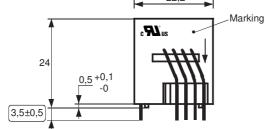
Connections: 1...4: 0,46\*0,46 mm

5..12: Ø 1 mm





**7AN UL-sign** 4646-X762-83 DC

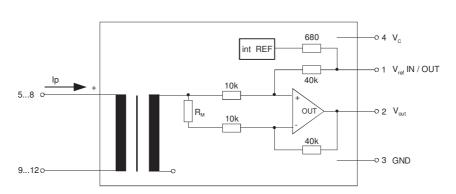


Tolerances grid distance ±0,25mm

DC= Date Code F = Factory

test dimension

#### Schematic diagram



#### Possibilities of wiring

 $(@ T_A = 85^{\circ}C)$ 

primary windings	primar RMS	y current maximal	output voltage RMS	turns ratio	primary resistance	wiring
$N_P$	I <sub>P</sub> [A]	$\hat{\mathbf{I}}_{P,max}\left[\mathbf{A}\right]$	$V_{out}(I_{PN})[V]$	$K_N$	$R_{P}\left[ m\Omega \right]$	
1	15	±51	2.5±0.625	1:2000	0.25	9 12
2	7,5	±25	2.5±0.625	2:2000	1.0	9 12
4	3,75	±12,5	2.5±0.625	4:2000	4	9 12

Hrsg.: KB-E	Bearb: Le	KB-PM: Ga.		freig.:SB
editor	designer	check		released

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#### **Electrical Data**

		min.	typ.	max.	Unit
V <sub>Ctot</sub>	Maximum supply voltage (without function)			7	V
lc	Supply Current with primary current	15m <i>A</i>	$+I_p*K_N+V_0$	out/RL	mA
lout,SC	Short circuit output current		±20		mA
$R_P$	Resistance / primary winding @ T <sub>A</sub> =25°C		1		$m\Omega$
Rs	Secondary coil resistance @ T <sub>A</sub> =85°C			67	Ω
$R_{i,Ref}$	Internal resistance of Reference input		670		$\Omega$
Ri,(Vout)	Output resistance of Vout			1	Ω
$R_L$	External recommended resistance of Vout	1			$k\Omega$
CL	External recommended capacitance of Vout			500	pF
$\Delta X_{Ti}/\Delta T$	Temperature drift of X@T <sub>A</sub> = -40 +85 °C			40	ppm/K
$\Delta V_0 = \Delta (V_{out} - V_{Ref})$	Sum of any offset drift including:		3,5	10	mV
$V_{0t}$	Longtermdrift of V <sub>0</sub>		2		mV
$V_{0T}$	Temperature drift von $V_0 @ T_A = -40 + 85$ °C		2		mV
$V_{0H}$	Hysteresis of $V_{out}$ @ $I_{P=0}$ (after an overload of 10 x $I_{PN}$	)		3	mV
$\Delta V_0/\Delta V_C$	Supply voltage rejection ratio			1	mV/V
V <sub>OSS</sub>	Offsetripple (with 1 MHz- filter first order)			30	mV
Voss	Offsetripple (with 100 kHz- filter firdt order)		4	8	mV
Voss	Offsetripple (with 20 kHz- filter first order)		1,2	2	mV
Ck	Maximum possible coupling capacity (primary – sec	condary)	5	10	pF
	Mechanical stress according to M3209/3 Settings: 10 – 2000 Hz, 1 min/Oktave, 2 hours			30g	

Inspection (Measurement after temperature balance of the samples at room temperature; SC = significant characteristic)

Vout (IP=IPN	ı) (V) M30	011/6: Output voltage	vs. external reference (I <sub>P</sub> =15A, 40-8	0Hz) 625±0,7	7% mV (SC)
Vout-VRef (	I <sub>P</sub> =0) (V) M32	226: Offset voltage		± 2.21	mV
V <sub>d</sub>	(V) M30	014: Test voltage, rr pin 1 – 4 vs. pir	•	1.8	kV
Ve	(AQL 1/S	<ol> <li>Partial discharge</li> <li>with V<sub>vor</sub> (RMS)</li> </ol>	ge voltage acc.M3024 (RMS)	1400 1750	V

#### Type Testing (Pin 1 - 4 to Pin 5 - 12)

$V_W$	HV transient test according to M3064 (1,2 μs / 50 μs-	8	kV	
V <sub>d</sub>	Testing voltage to M3014	(5 s)	3.6	kV
Ve	Partial discharge voltage acc.M3024 (RMS)		1400	V
	with V <sub>vor</sub> (RMS)		1750	V

#### Applicable documents

Current direction: A positive output current appears at point I<sub>S</sub>, by primary current in direction of the arrow.

Housing and bobbin material UL-listed: Flammability class 94V-0.

Enclosures according to IEC529: IP50.

Further standards UL 508 file E317483, category NMTR2 / NMTR8

Operating temperature of the current sensor and the primary conductor must not exceed 105°C

"The color of the plastic material is not specified and the current sensor can be supplied in different colors

(e.g. brown, black, white, natural). This has no effect on the specifications or UL approval.

Hrsg.: KB-E	Bearb: Le	KB-PM: Ga.		freig.:SB
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#### Explanation of several of the terms used in the tablets (in alphabetical order)

tr: Response time (describe the dynamic performance for the specified measurement range), measured as delay time at  $I_P = 0.9 \cdot I_{PN}$  between a rectangular current and the output voltage  $V_{OUI}$  ( $I_D$ )

 $\Delta t$  (I<sub>Pmax</sub>): Delay time (describe the dynamic performance for the rapid current pulse rate e.g short circuit current) measured between I<sub>Pmax</sub> and the output voltage V<sub>out</sub>(I<sub>Pmax</sub>) with a primary current rise of dip/dt  $\geq$  100 A/ $\mu$ s.

 $V_0$ : Offset voltage between  $V_{out}$  and the rated reference voltage of  $V_{\text{ref}}=2.5V.$   $V_o=V_{out}(0)\,$  - 2.5V

 $U_{PD}$  Rated discharge voltage (recurring peak voltage separated by the insulation) proved with a sinusoidal voltage  $V_e$   $U_{PD} = \sqrt{2 * V_e / 1.5}$ 

V<sub>vor</sub> Defined voltage is the RMS valve of a sinusoidal voltage with peak value of 1,875 \* U<sub>PD</sub> required for partial discharge test in IEC 61800-5-1

 $V_{vor} = 1.875 * U_{PD} / \sqrt{2}$ 

V<sub>sys</sub> System voltage RMS value of rated voltage according to IEC 61800-5-1

Vwork Working voltage voltage according to IEC 61800-5-1 which occurs by design in a circuit or across insulation

V₀H: Zero variation of V₀ after overloading with a DC of tenfold the rated value

V<sub>0t</sub>: Long term drift of V₀ after 100 temperature cycles in the range -40 bis 85 °C.

X: Permissible measurement error in the final inspection at RT, defined by

 $X = 100 \cdot \left| \frac{V_{out}(I_{PN}) - V_{out}(0)}{0,625V} - 1 \right| \%$ 

X<sub>ges</sub>(I<sub>PN</sub>): Permissible measurement error including any drifts over the temperature range by the current measurement I<sub>PN</sub>

 $X_{ges} = 100 \cdot \left| \frac{V_{out} (I_{PN}) - 2.5V}{0.625V} - 1 \right| \% \text{ or } X_{ges} = 100 \cdot \left| \frac{V_{out} (I_{PN}) - V_{ref}}{0.625V} - 1 \right| \%$ 

 $\varepsilon_{\rm L} : \qquad \qquad \text{Linearity fault defined by} \qquad \varepsilon_{\rm L} = 100 \cdot \left| \frac{I_{\rm P}}{I_{\rm PN}} - \frac{V_{\it out}(I_{\it P}) - V_{\it out}(0)}{V_{\it out}(I_{\it PN}) - V_{\it out}(0)} \right| \, \%$